NSN 5961-00-887-5614

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-887-5614 **Inclosure Material:** Glass **Overall Length:** 0.357 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.235 inches **End Application:** Automated radar terminal system 3a (arts3a) **Mounting Method: Terminal Terminal Circle Diameter:** 0.030 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 64.1 reverse voltage, instantaneous **Current Rating Per Characteristic:** 5.00 milliamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0